

45 V, 1 A PNP medium power transistors Rev. 1 — 29 April 2019

Product data sheet

1. Product profile

1.1. General description

PNP medium power transistors in a medium power SOT223 (SC73) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package	NPN comlement	
	Nexperia	JEDEC	
BCP51T	SOT223	SC-73	BCP54T
BCP51-10T			BCP54-10T
BCP51-16T			BCP54-16T

1.2. Features and benefits

- High collector current capability I_C and I_{CM}
- Three current gain selections
- High power dissipation capability
- AEC-Q101 qualified

1.3. Applications

- Linear voltage regulators
- MOSFET drivers
- High-side switches
- Power management
- Amplifiers

1.4. Quick reference data

Table 2. Quick reference data

T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-45	V
I _C	collector current		-	-	-1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	-	-	-2	А

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45 V, 1 A PNP medium power transistors

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
h _{FE}	DC current gain	ent gain					_
	BCP51T	V _{CE} = -2 V; I _C = -150 mA	[1]	63	-	250	
	BCP51-10T		[1]	63	-	160	
	BCP51-16T		[1]	100	-	250	

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$

2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	Ċ
2	С	collector		B□
3	E	emitter		
4	С	collector	1 2 3	E sym132

3. Ordering information

Table 4. Ordering	g information	1				
Type number	Package					
	Name	Description	Version			
BCP51T	SC-73	plastic, surface-mounted package with increased heatsink;	SOT223			
BCP51-10T		4 leads				
BCP51-16T						

4. Marking

Table 5. Marking				
Type number	Marking code			
BCP51T	BCP51T			
BCP51-10T	P5110T			
BCP51-16T	P5116T			

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

T_{amb} = 25 °C unless otherwise specified.

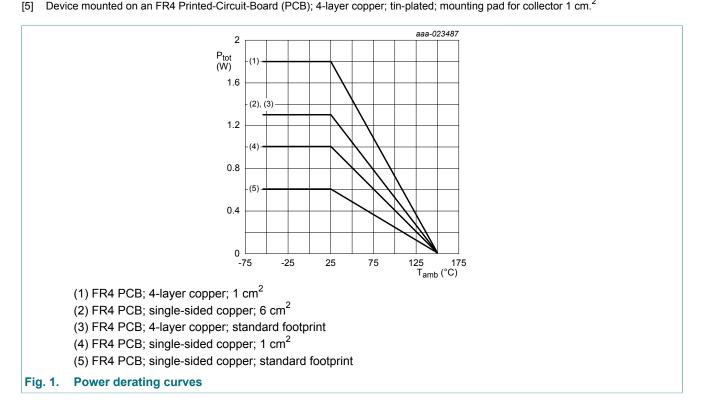
Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	open emitter		-45	V
V _{CEO}	collector-emitter voltage	open base		-	-45	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		-2	А
I _B	base current			-	-0.2	А
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	-0.3	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.6	W
			[2]	-	1	W
			[3]	-	1.3	W
			[4]	-	1.3	W
			[5]	-	1.8	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

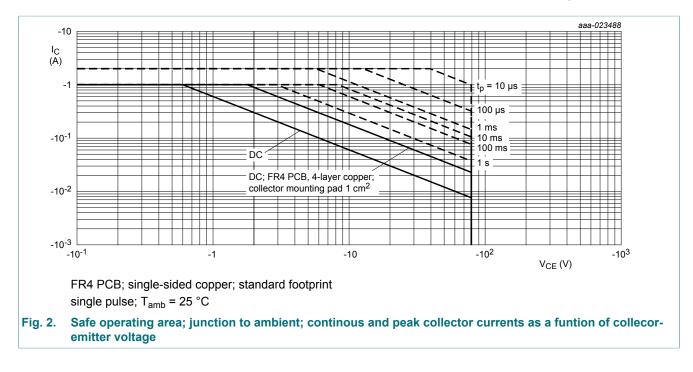
Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm². [2]

Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm². [3] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint. [4]

Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm.²



45 V, 1 A PNP medium power transistors



6. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient	thermal resistance from junction to ambient	in free air	[1]	-	-	209	K/W
		[2]			125	K/W	
			[3]			97	K/W
			[4]	-	-	97	K/W
			[5]	-	-	70	K/W
R _(j-sp)	thermal resistance from junction to solder point			-	-	18	K/W

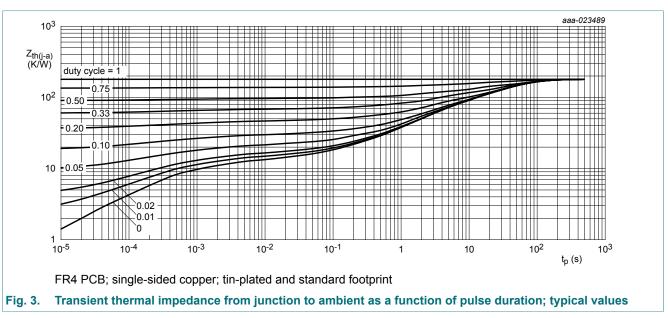
Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint. [1]

Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 1 cm². Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated; mounting pad for collector 6 cm². [2]

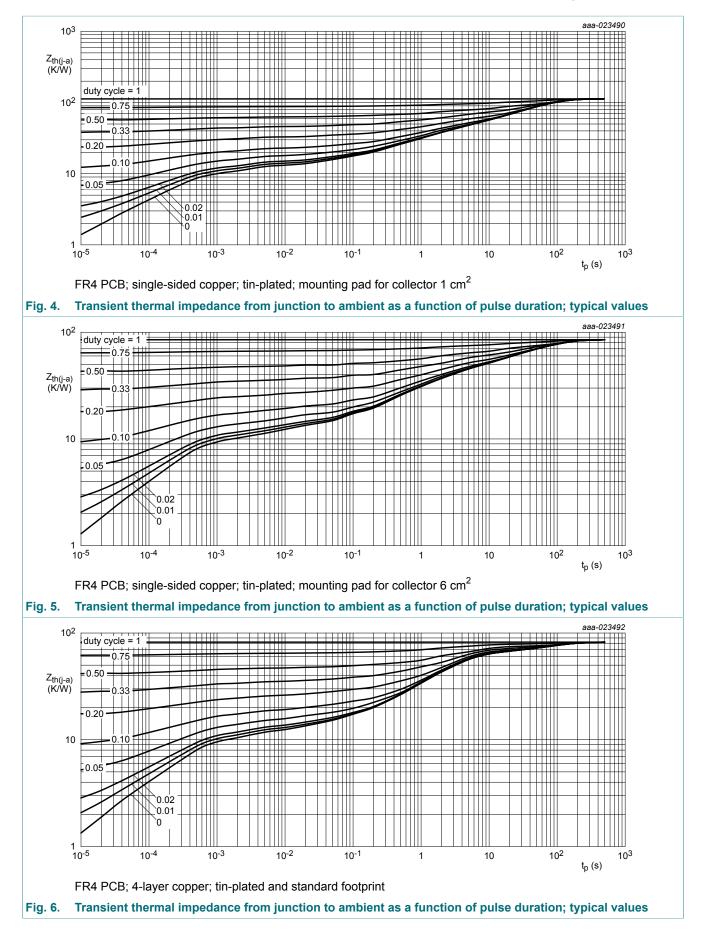
[3]

Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint. [4]

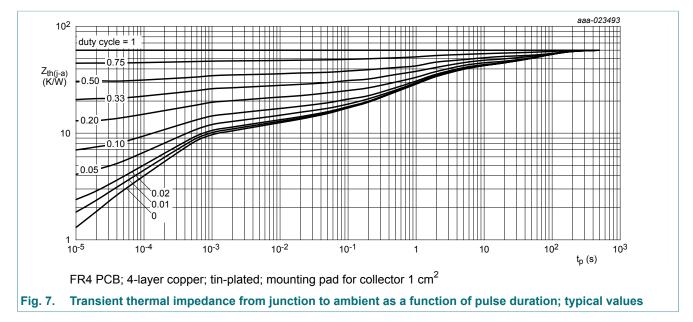
[5] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated; mounting pad for collector 1 cm².



45 V, 1 A PNP medium power transistors



45 V, 1 A PNP medium power transistors



7. Characteristics

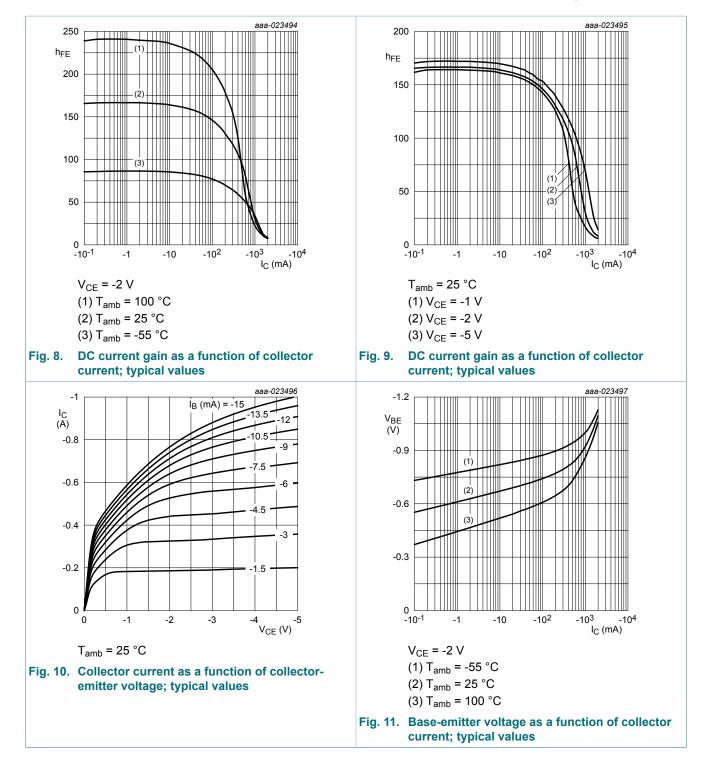
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

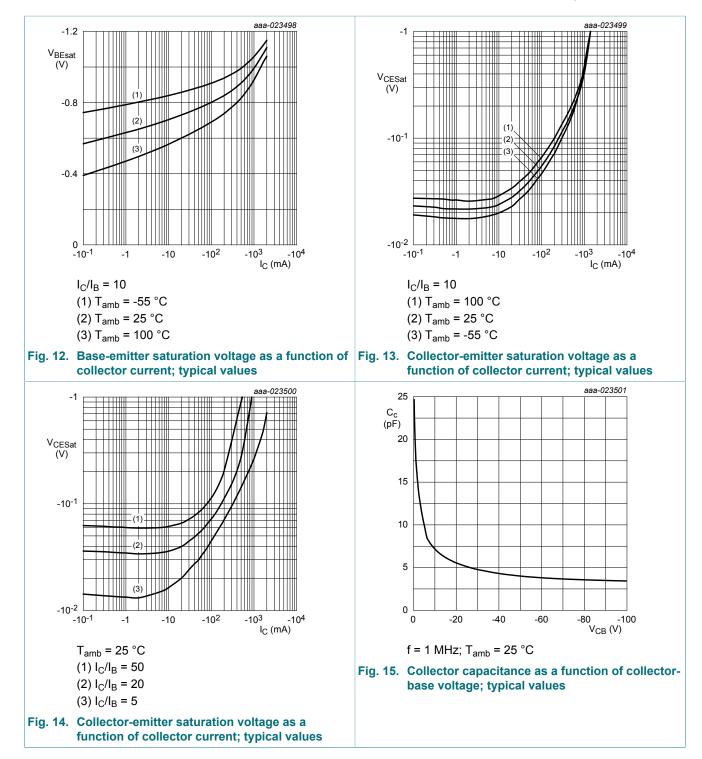
Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
V _{(BR)CBO}	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A		-45	-		V		
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -2 mA; I _E = 0 A		-45	-		V		
V _{(BR)EBO}	emitter-base breakdown voltage	I _E = -100 μA; I _C = 0 A		-5	-		V		
I _{CBO}	collector-base	V _{CB} = -30 V; I _E = 0 A		-	-	-100	nA		
	cut-off current	V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C		-	-	-10	μA		
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A		-	-	-100	nA		
h _{FE}	DC current gain	DC current gain							
BC	BCP51T, -10T, -16T	V _{CE} = -2 V; I _C = -5 mA		63	-	-			
		V _{CE} = -2 V; I _C = -500 mA	[1]	40	-	-			
	BCP51T	V _{CE} = -2 V; I _C = -150 mA	[1]	63	-	250			
	BCP51-10T	V _{CE} = -2 V; I _C = -150 mA	[1]	63	-	160			
	BCP51-16T	V _{CE} = -2 V; I _C = -150 mA	[1]	100	-	250			
V _{CEsat}	collector-emitter saturation voltage	I _C = -500 mA; I _B = -50 mA	[1]	-	-	-500	mV		
V _{BE}	base-emitter voltage	V _{CE} = -2 V; I _C = -500 mA	[1]	-	-	-1	V		
f _T	transition frequency	V _{CE} = -5 V; I _C = -50 mA; f = 100 MHz		100	140	-	MHz		
Cc	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz		-	7	-	pF		

[1] pulsed; $t_p \le 300 \ \mu s$; $\delta \le 0.02$

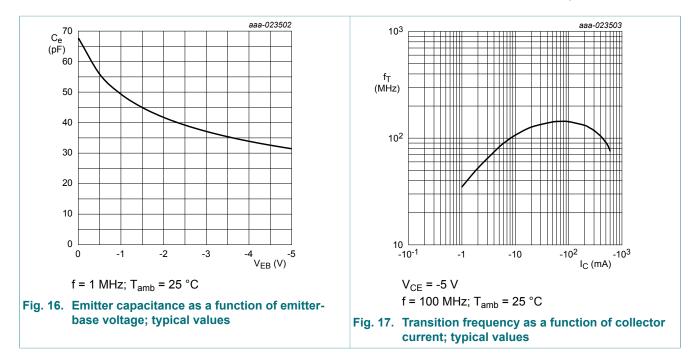
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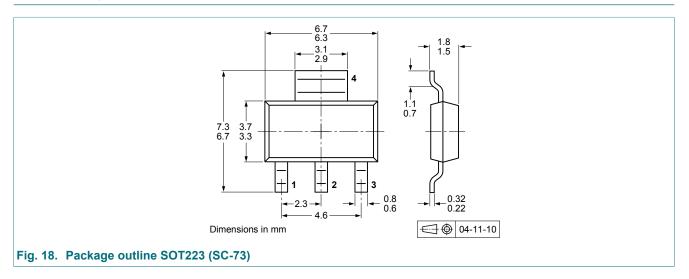


8. Test information

8.1. Quality information

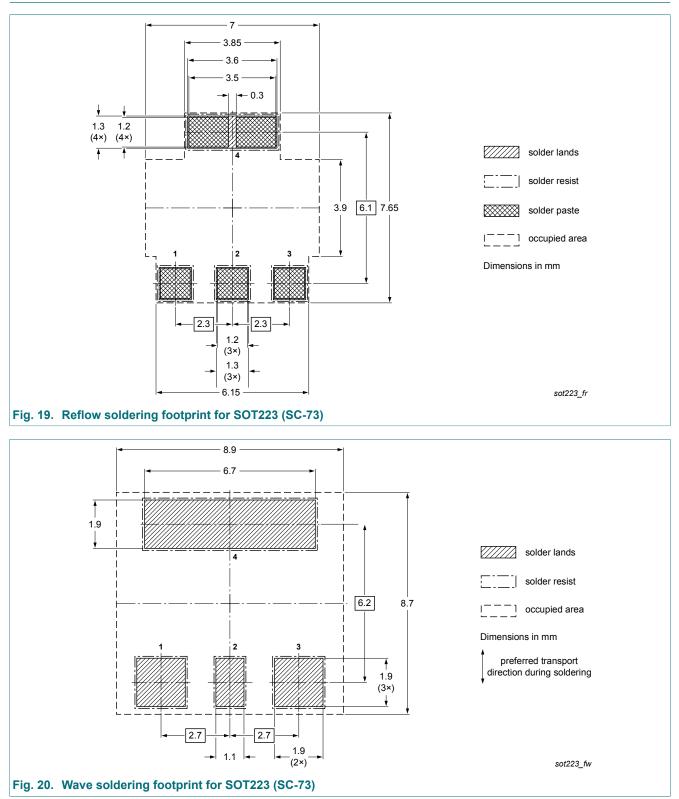
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

9. Package outline



45 V, 1 A PNP medium power transistors

10. Soldering



45 V, 1 A PNP medium power transistors

11. Revision history

Table 9. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP51T_SER v.1	20190429	Product data sheet	-	-

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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45 V, 1 A PNP medium power transistors

Contents

1. Product profile	1
1.1. General description	1
1.2. Features and benefits	1
1.3. Applications	1
1.4. Quick reference data	1
2. Pinning information	2
3. Ordering information	2
4. Marking	2
5. Limiting values	3
6. Thermal characteristics	5
7. Characteristics	7
8. Test information	10
8.1. Quality information	10
9. Package outline	10
10. Soldering	
11. Revision history	12
12. Legal information	

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